

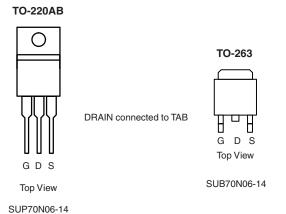


# N-Channel 60-V (D-S), 175 °C MOSFET

PRODUCT SUMMARY				
V <sub>(BR)DSS</sub> (V)	$r_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
60	0.014	70 <sup>a</sup>		







G S

N-Channel MOSFET

Ordering Information: SUB70N06-14

SUB70N06-14-E3 (Lead (Pb)-free) SUP70N06-14-E3 (Lead (Pb)-free)

ABSOLUTE MAXIMUM RAT	25 0, 0111000 01101		1.114	1114	
Parameter Gate-Source Voltage		Symbol	Limit	Unit V	
		$V_{GS}$	± 20		
Continuous Drain Current (T <sub>J</sub> = 175 °C)	T <sub>C</sub> = 25 °C	- I <sub>D</sub>	70 <sup>a</sup>	A	
	T <sub>C</sub> = 100 °C		49		
Pulsed Drain Current		I <sub>DM</sub>	160		
Avalanche Current		I <sub>AR</sub>	70		
Repetitive Avalanche Energy <sup>b</sup>	L = 0.1 mH	E <sub>AR</sub>	180	mJ	
Power Dissipation	T <sub>C</sub> = 25 °C (TO-220AB and TO-263)	ם	142 <sup>c</sup>	W	
	T <sub>A</sub> = 25 °C (TO-263) <sup>d</sup>	$P_{D}$	3.7		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Limit	Unit	
Junction-to-Ambient	PCB Mount (TO-263) <sup>d</sup>	. R <sub>thJA</sub>	40	°C/W	
	Free Air (TO-220AB)		62.5		
Junction-to-Case		R <sub>thJC</sub>	1.05		

#### Notes:

- a. Package limited.
- b. Duty cycle  $\leq$  1 %.
- c. See SOA curve for voltage derating.
- d. When Mounted on 1" square PCB (FR-4 material).

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm.

\* Pb containing terminations are not RoHS compliant, exemptions may apply.

## **SUP/SUB70N06-14**

## Vishay Siliconix



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	<u> </u>					
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_{DS} = 1$ mA	2.0	3.0	4.0	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
	I <sub>DSS</sub>	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$			50	
		V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 175 °C			150	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	70			Α
Drain-Source On-State Resistance <sup>a</sup>		$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$			0.014	
	r <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}, T_J = 125 ^{\circ}\text{C}$			0.023	Ω
		$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}, T_J = 175 ^{\circ}\text{C}$			0.028	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 30 A	25	50		S
Dynamic <sup>b</sup>	•			•		
Input Capacitance	C <sub>iss</sub>			2400		pF
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		490		
Reverse Transfer Capacitance	C <sub>rss</sub>			130		
Total Gate Charge <sup>c</sup>	Qg	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 60 \text{ A}$		45	70	nC
Gate-Source Charge <sup>c</sup>	$Q_{gs}$			12		
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			16		
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>	$V_{DD}$ = 30 V, $R_L$ = 0.47 $\Omega$ $I_D$ $\cong$ 60 A, $V_{GEN}$ = 10 V, $R_G$ = 2.5 $\Omega$		13	30	ns
Rise Time <sup>c</sup>	t <sub>r</sub>			11	30	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			30	60	
Fall Time <sup>c</sup>	t <sub>f</sub>			11	25	
Source-Drain Diode Ratings and Cha	aracteristics 7	<sub>C</sub> = 25 °C <sup>b</sup>				
Continuous Current	I <sub>S</sub>				70	А
Pulsed Current	I <sub>SM</sub>				160	
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_F = 70 \text{ A}, V_{GS} = 0 \text{ V}$			1.4	V
Reverse Recovery Time	t <sub>rr</sub>			47		ns
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>	I <sub>F</sub> = 60 A, di/dt = 100 A/μs		3.5		Α
Reverse Recovery Charge	Q <sub>rr</sub>			0.08		μС

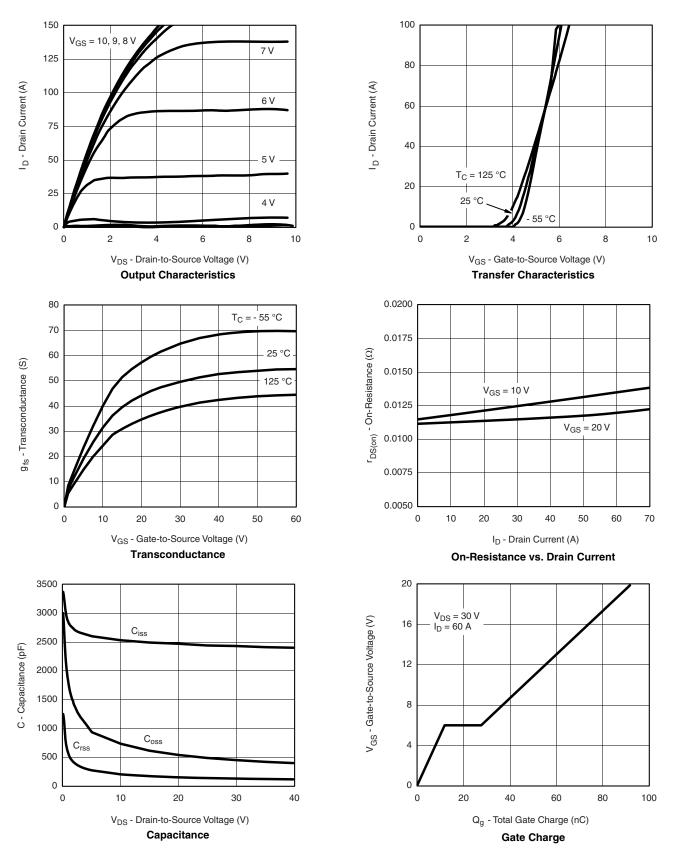
### Notes:

- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



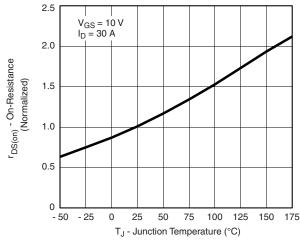
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



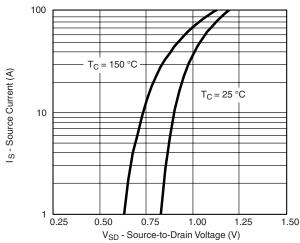
## Vishay Siliconix

# VISHAY.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

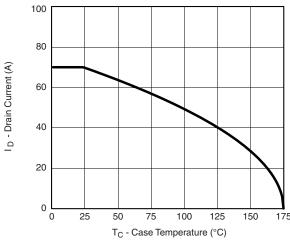


On-Resistance vs. Junction Temperature

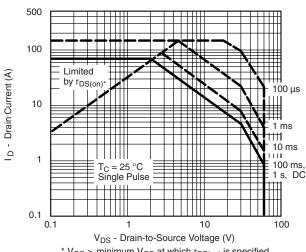


Source-Drain Diode Forward Voltage

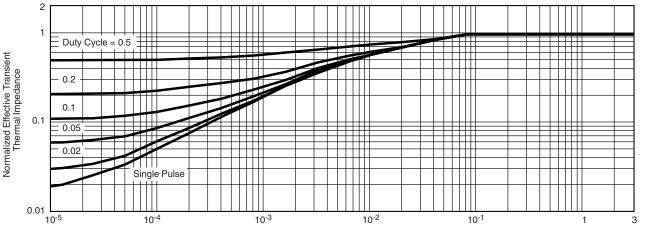
### THERMAL RATINGS



Maximum Avalanche and Drain Current vs. Case Temperature



 $^{\star}$  V<sub>GS</sub> > minimum V<sub>GS</sub> at which  $r_{DS(on)}$  is specified **Safe Operating Area** 



Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?70291">http://www.vishay.com/ppg?70291</a>.



### **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

## **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000